



INTERNATIONAL ATOMIC ENERGY AGENCY
UNITED NATIONS EDUCATIONAL, SCIENTIFIC AND CULTURAL ORGANIZATION



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WORKSHOP ON SPACE PHYSICS:
"Materials in Microgravity"
27 February - 17 March 1989

"Introduction to Materials: Gordon Conference Microgravity 1987"

E. KALDIS
ETH
Zurich, Switzerland

Please note: These are preliminary notes intended for internal distribution only.

α -HgI₂, THE MATERIAL

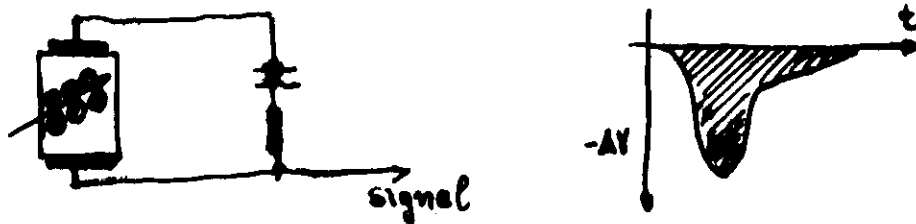
Importance for applications

x- and γ -ray ROOM TEMPERATURE semiconductor detector

↓
due to band gap 2 eV
no thermal noise
at room temperature

On the contrary, presently used detectors need refrigeration due to small band gap

Silicon $\Delta E = 1.08 \text{ eV}$
Germanium $= 0.67 \text{ eV}$



Possibility to work without refrigeration brings enormous advantages for technological applications

Additional advantage of α -HgI₂
much stronger absorption

↓
also need for very large crystals (thick)
for quantitative γ -ray absorption



γ -Ray detectors

State of the art:

- Miniature Geiger-counters and γ -spectrometers
- Portable devices for nuclear plant safety
- Miniaturized EDAX-system for interplanetary vehicles
- Portable EDAX-system for mineral prospecting (for $Z > Al$ x-ray penetrates the atmosphere)

Expected breakthrough
if better crystals

ARRAYS OF DETECTORS

- Tomography
- γ -cameras

α - HgI_2 , presently, best RT nuclear detector

Theoretically calculated resolution 0,8%

For 60 keV radiation (Am^{241}) $\rightarrow$ 0.5 keV

best Detector	1.15 keV
presently, good detectors	2-3 keV (3-4%)

Applications (counters and γ -spectrometers):

- | | |
|----------------------------|--------------------|
| - Nuclear medicine | - EDAX-systems |
| - Tomography | - nuclear sciences |
| - Environmental Protection | - space sciences |
| | - nuclear plants |
| | - defence |

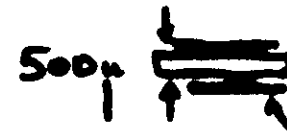
X-RAY DETECTORS

→ Ionization efficiency

$$\begin{aligned} \text{HgI}_2) \frac{\text{band gap}}{\text{energy to produce el-hole pair}} &= \frac{2.2\text{eV}}{4.2\text{eV}} = 52\% \\ \text{Si)} &= 30\% \end{aligned}$$

Detector Fabrication

→ Electrodes



Pd-Electrodes 100-200Å

→ BeO Ceramic Substrate

low dielectric const.
excell. thermal cond

→ Encapsulant

Poly-methylmethacrylate (PMMA)
not reprod. thickness; cracks
Poly-dichloro-di-para-nylylene
Un. Carbide Paracene - C. Vaku

Advantages of room temperature detectors:

- Miniaturization
(in contrast to scintillators or Si, Ge detectors) } arrays { tomography, γ-cameras
- easy measurements: human + environm. protection
- Remote sensing → spacecrafts

Drawbacks of α-HgI₂ detectors:

- Low MOBILITY of HOLES
- μ (cm²/V.s)
 electrons $\mu_e \approx 100.0$ holes $\mu_h = 4.0$

This is due to the existence of TRAPS in the crystal lattice

- VERY EASY PLASTIC DEFORMATION

creating many traps: large crystals deformate under their own weight, particularly at the growth temperature.

Amplification Electronics

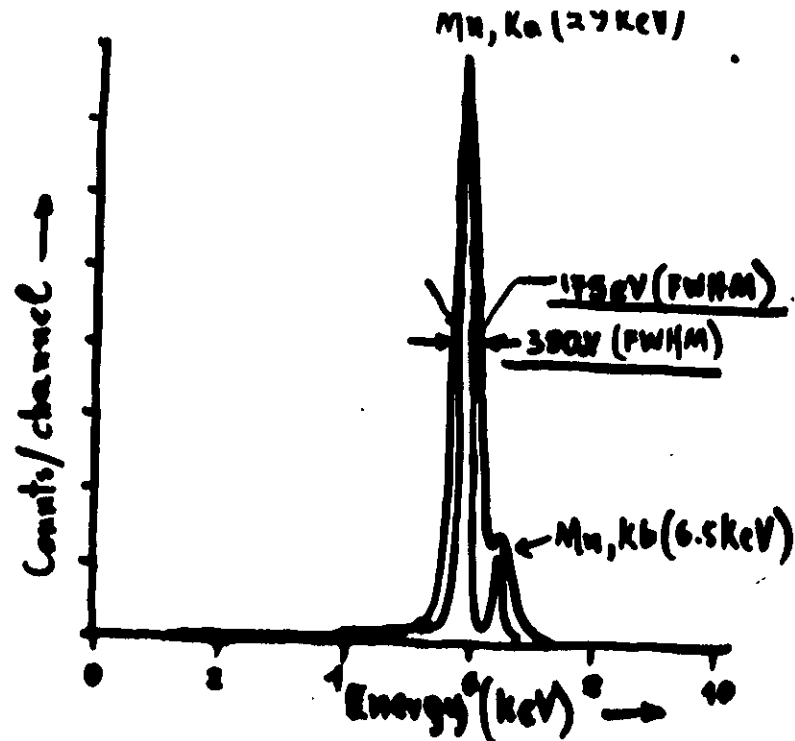
Ultra-low noise preamplifiers
without cryogenically cooled FET's
necessary

- lowest commercially available
500 eV (FWHM) for HgI_2 .

Cryogenic cooling. Deencapsulation
Remounting low-noise
Substrates

Pulsed-light feedback
cooling input FET's with mini-thermo-
electric coolers: ($0.5 \text{ m}^2 <$), 250 mV, $70-10^\circ\text{C}$
180 eV (FWHM)

DETECTION OF O K-line
(523 eV)



Source Fe-55

Detector HgI_2 ($1 \text{ mm}^2 \times 400 \mu\text{m}$)

at Room TEMPERATURE

Preamplifier: Pulsed light feedback

Input FET

1. ROOM TEMPERATURE

2. CRYOGENICALLY COOLED

Al, K (1.5 eV)
FWHM 145 eV

Entrance electrode
negative. X-ray small
holes travel very quickly
small distances

